

isc N-Channel MOSFET Transistor

AOTF7N70

FEATURES

- Drain Current –I_D= 7A@ T_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V_{DSS}= 700V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 1.8 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	700	v				
V _{GS}	Gate-Source Voltage-Continuous	±30	V				
ID	Drain Current-Continuous 7		A				
I _{DM}	Drain Current-Single Pluse	24	A				
P _D	Total Dissipation @T _c =25℃	38.5	w				
TJ	Max. Operating Junction Temperature	-55~150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

PARAMETER

Thermal Resistance, Junction to Case

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL

Rth j-c

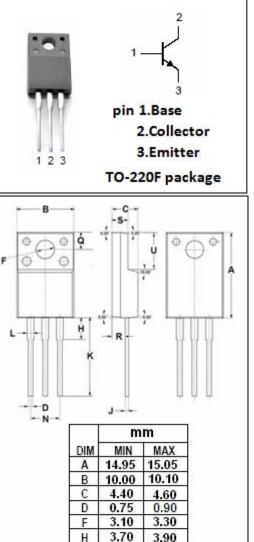
isc website: <u>www.iscsemi.com</u> ¹ *isc & iscsemi* is registered trademark

UNIT

°C/W

MAX

3.25



0.50

13.4

1.10

5.00

2.70

2.20

2.65

6.40

J

N

0

R

s

U

0.70

13.6

1.30

5.20

2.90

2.40

6.60

2.90



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮРЕ	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	700			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = 5V; I _D = 0.25mA	3		4.5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 3.5A			1.8	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 700V; V _{GS} = 0 V _{DS} = 560V; V _{GS} = 0@T _J = 55℃			1 10	μA
V_{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0			1	v



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